

MAC97A6,MAC97A8 Series

- Description:**

Logic level sensitive gate triac intended to interfaced directly to microcontrollers,logic integrated circuits and other low power gate trigger circuits.

- Applications**

This device is suitable for low power AC switching application,phase control application such as fan speed and temperature modulation control,lighting control and static switching relay.

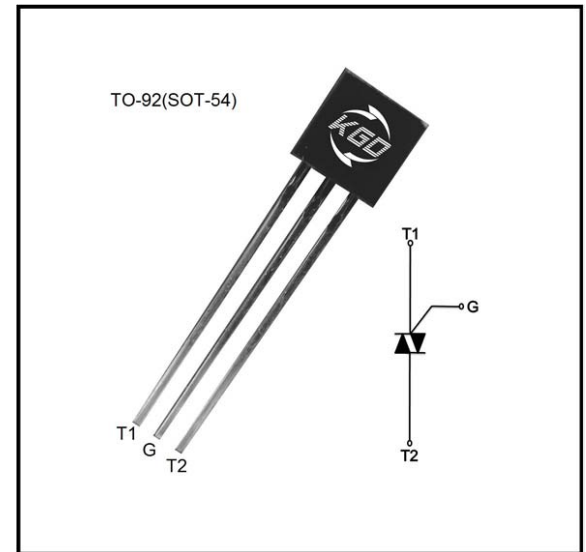
- Features:**

Blocking voltage to 400/600V

On-state RMS current to 0.8A

Non-repetitive peak on-state current to 8A

- Absolute Maximum Ratings**



Symbol	Parameter	Conditions	Value		Unit
			97A6	97A8	
V_{DRM}	Repetitive peak off-state voltage	$T_J=25^{\circ}\text{C}$	400	600	V
V_{RRM}	Repetitive peak Reverse voltage	$T_J=25^{\circ}\text{C}$	400	600	V
$I_{T(RMS)}$	RMS on-state current (full sine wave)	$T_c=110^{\circ}\text{C}$	0.8		A
$I_{T(av)}$	Average on-state current (full sine wave)	$T_c=110^{\circ}\text{C}$	0.5		A
I_{TSM}	Non-repetitive surge peak On-state current (One full cycle,sine wave, $T_c=110^{\circ}\text{C}$)	$t_p=10\text{ms}$	8		A
		$t_p=8.3\text{ms}$	8.3		
I^2t	I^2t Value for fusing	$t_p=10\text{ms}$	0.32		A^2S
I_{GM}	Peak gate current	$t_p \leq 2\mu\text{s}, T_J=80^{\circ}\text{C}$	1		A
$P_{G(AV)}$	Average gate power dissipation		0.1		W
		$t_p \leq 10\text{ms}, T_J=80^{\circ}\text{C}$			
PGM	Peak gate power dissipation		1		W
T_{STG}	Storage temperature		-40	150	$^{\circ}\text{C}$
T_J	Junction temperature		-40	125	$^{\circ}\text{C}$

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● Electrical Characteristics

Symbol	Conditions	Quadrant	Value		Unit
			MIN	MAX	
I_{GT}	$V_D=12V, R_L=33\Omega$	I - II -III	/	5	mA
		IV	/	7	
V_{GT}		ALL	/	1.5	V
V_{GD}	$V_D=V_{DRM}, R_L=3.3K\Omega, T_J=125^\circ C$	ALL	0.2	/	V
I_L	$I_G=1mA$	ALL	/	10	mA
I_H	$I_T=200mA$		/	5	mA
dv/dt	$V_{DM}=67\%V_{DRM}$, gate open, $T_J=125^\circ C$		25	/	V/ μs

● Electrical Characteristics

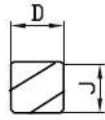
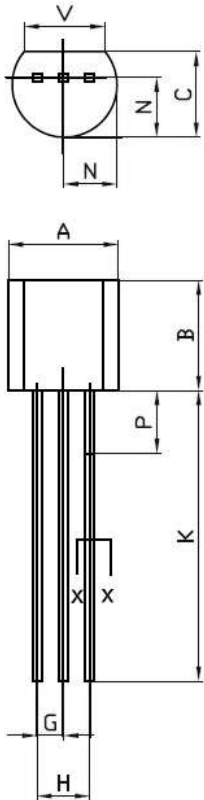
Symbol	Parameter	Numerical	Unit
V_{TM}	$I_T=1.1A, t_p=380\mu s$ $T_J=25^\circ C$	1.5	V
I_{DRM}	$V_D=V_{DRM}, V_R=V_{RRM}$ $T_J=25^\circ C$	5	μA
I_{RRM}	$T_J=125^\circ C$	0.1	mA

● Thermal Characteristics

Symbol	Parameter	Numerical(MAX)	Unit
$R_{th(j-c)}$	Junction to case(AC)	75	$^\circ C/W$
$R_{th(j-a)}$	Junction to ambient(AC)	150	$^\circ C/W$

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● Package Outline Dimensions

TO-92 (SOT-54)

**SECTION
X-X**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.45	5.2	0.175	0.205
B	4.32	5.33	0.170	0.210
C	3.18	4.19	0.125	0.165
D	0.407	0.533	0.016	0.021
G	1.15	1.39	0.045	0.055
H	2.42	2.66	0.095	0.105
J	0.39	0.50	0.015	0.020
K	12.70	-	0.500	-
N	2.04	2.66	0.080	0.105
P	-	2.54	-	0.100
V	3.43	-	0.135	-

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FIG.1: Maximum power dissipation versus average on-state current.

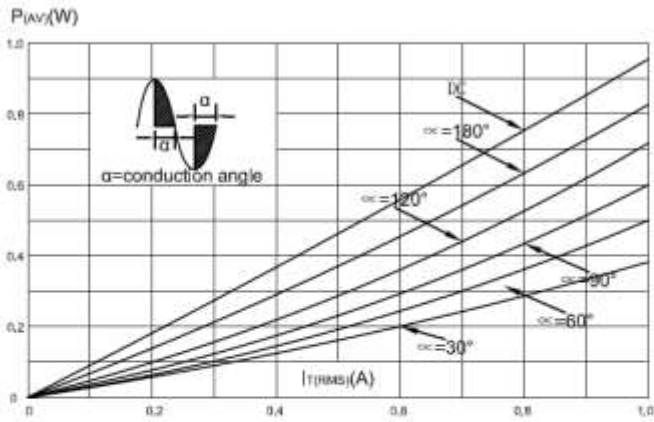


FIG.2: RMS on-state current versus case temperature.

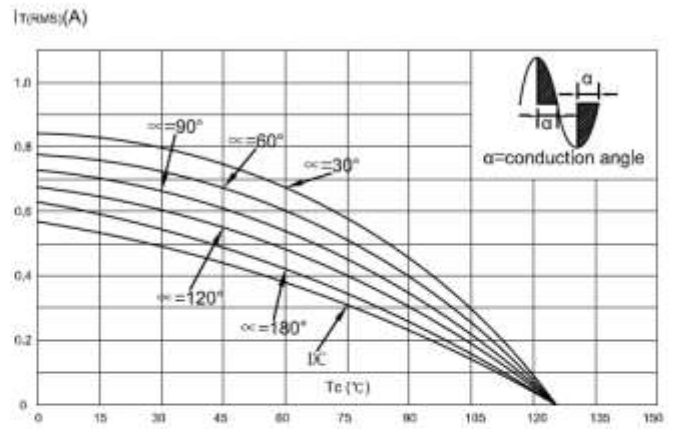


FIG.3: On-state characteristics (maximum values)

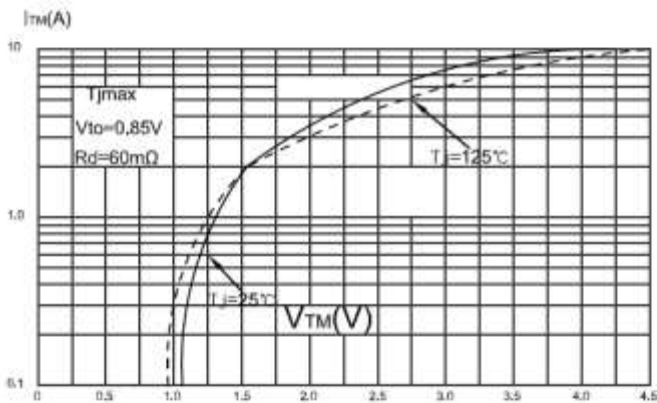


FIG.4: Surge peak on-state current versus number of cycles.

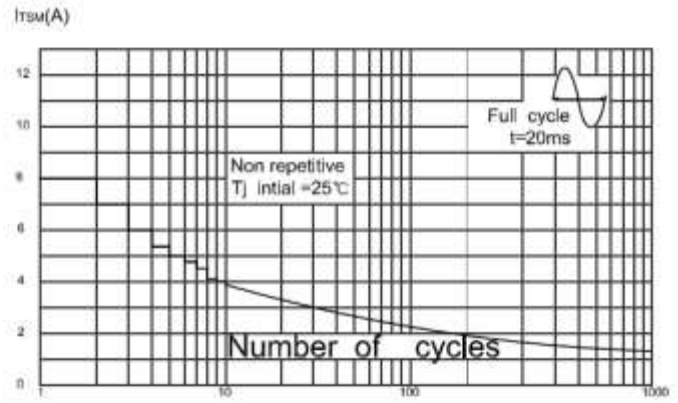


FIG.5: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

